

BUY69A

HIGH VOLTAGE NPN SILICON TRANSISTOR

- STM PREFERRED SALESTYPE -
- NPN TRANSISTOR
- HIGH VOLTAGE CAPABILITY
- HIGH CURRENT CAPABILITY
- FAST SWITCHING SPEED
- HIGH POWER TO-3 PACKAGE

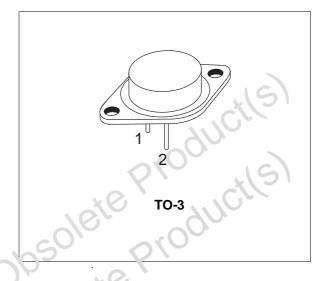
APPLICATIONS:

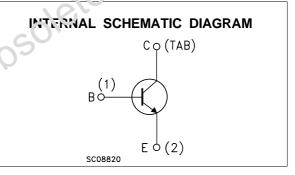
- HORIZONTAL DEFLECTION FOR COLOUR ΤV
- SWITCHING REGULATORS

DESCRIPTION

osolet

The BUY69A is a silicon Multi-Epitaxial mesa NPN transistor in Jedec TO-3 metal case. It is intended for horizontal deflection output stage of CTV receivers and high voltage, fast switching and industrial applications. ete Product(S) -





ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit	
/ _{CES}	Collector-Emitter Voltage (V _{BE} = 0)	1000	V	
VCEO	Collector-Emitter Voltage (I _B = 0)	400	V	
V_{EBO}	Emitter-Base Voltage $(I_C = 0)$	8	V	
lc	Collector Current	10		
Ісм	Collector Peak Current (tp \leq 10 ms)	15	A	
IB	Base Current	3	A	
P _{tot}	Total Dissipation at $T_c \le 25$ °C	100	W	
T _{stg}	Storage Temperature	-65 to 200	°C	
Tj	Max. Operating Junction Temperature	200	°C	

THERMAL DATA

R _{thj-case} Thermal Resistance Junction-case	Max	1.75	°C/W
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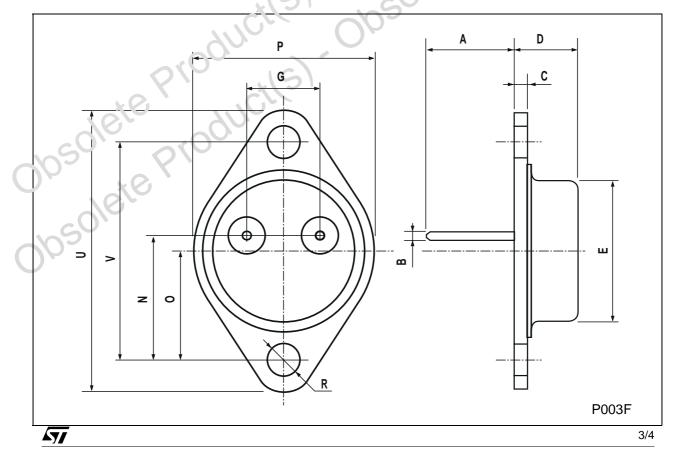
ELECTRICAL CHARACTERISTICS (T_{case} = 25 °C unless otherwise specified)

$\begin{array}{c c} & & & & \\ \hline \\ \hline$	Collector Cut-off Current ($V_{BE} = 0$) Emitter Cut-off Current ($I_C = 0$) Collector-Emitter Sustaining Voltage ($I_B = 0$) Collector-Emitter Saturation Voltage Base-Emitter Saturation Voltage DC Current Gain Transition Frequency Second Breakdown Collector Current Turn on Time Storage Time	$V_{CE} = 1000 V$ $V_{EB} = 8 V$ $I_{C} = 100 mA$ $I_{C} = 8 A$ $I_{C} = 8 A$ $I_{C} = 2.5 A$ $I_{C} = 0.5 A$ $V_{CE} = 25 V$ $I_{C} = 5 A$ $I_{B1} = 1 A$	$I_B = 2.5 \text{ A}$ $I_B = 2.5 \text{ A}$ $V_{CE} = 10 \text{ V}$ $V_{CE} = 10 \text{ V}$ $V_{CE} = 250 \text{ V}$	400	10	1 1 3.2 2.2	mA mA V V V MHz A
$\begin{array}{c} (() \\ V_{CEO(sus)} \\ () \\ V_{CE(sat)*} \\ C \\ S \\ () \\ V_{BE(sat)*} \\ B \\ S \\ F \\ S \\ F \\ S \\ F \\ S \\ f_T \\ I_{S/b}^{**} \\ C \\ T \\ t_{on} \\ T \\ t_{s} \\ t_{s} \\ F \\ \end{array}$	(I _C = 0) Collector-Emitter Sustaining Voltage (I _B = 0) Collector-Emitter Saturation Voltage Base-Emitter Saturation Voltage DC Current Gain Transition Frequency Second Breakdown Collector Current Turn on Time	$I_{C} = 100 \text{ mA}$ $I_{C} = 8 \text{ A}$ $I_{C} = 8 \text{ A}$ $I_{C} = 2.5 \text{ A}$ $I_{C} = 0.5 \text{ A}$ $V_{CE} = 25 \text{ V}$ $I_{C} = 5 \text{ A}$ $I_{B1} = 1 \text{ A}$	I _B = 2.5 A V _{CE} = 10 V V _{CE} = 10 V	15	10	3.2	V V V MHz
$\begin{array}{c} V_{CE(sat)} & s \\ (I \\ V_{CE(sat)} & S \\ S \\ V_{BE(sat)} & s \\ h_{FE} & C \\ f_T & T \\ I_{s/b} & S \\ C \\ \hline t_{on} & T \\ t_{s} & s \\ t_s & F \end{array}$	Sustaining Voltage (I _B = 0) Collector-Emitter Saturation Voltage Base-Emitter Saturation Voltage DC Current Gain Transition Frequency Second Breakdown Collector Current Turn on Time	$I_{C} = 8 A$ $I_{C} = 8 A$ $I_{C} = 2.5 A$ $I_{C} = 0.5 A$ $V_{CE} = 25 V$ $I_{C} = 5 A$ $I_{B1} = 1 A$	I _B = 2.5 A V _{CE} = 10 V V _{CE} = 10 V	15			V V MHz
$\begin{array}{c} & \text{S} \\ V_{\text{BE}(\text{sat})} \ast & \text{B} \\ \text{S} \\ & \text{h}_{\text{FE}} \ast & \text{D} \\ & f_{\text{T}} & \text{T} \\ & I_{\text{s}/\text{b}} \ast \ast & \text{S} \\ & I_{\text{s}/\text{b}} \ast \ast & \text{S} \\ & I_{\text{s}/\text{b}} \ast & I_{\text{s}/\text{b}} \end{array} $	Saturation Voltage Base-Emitter Saturation Voltage DC Current Gain Transition Frequency Second Breakdown Collector Current Turn on Time	$I_{C} = 8 A$ $I_{C} = 2.5 A$ $I_{C} = 0.5 A$ $V_{CE} = 25 V$ $I_{C} = 5 A$ $I_{B1} = 1 A$	I _B = 2.5 A V _{CE} = 10 V V _{CE} = 10 V				V MHz
$\begin{array}{c c} & S \\ \hline h_{FE}* & C \\ \hline f_T & T \\ \hline I_{s/b}** & S \\ \hline C \\ \hline \\ \hline t_{on} & T \\ \hline t_s & S \\ \hline t_s & F \end{array}$	Saturation Voltage DC Current Gain Transition Frequency Second Breakdown Collector Current Turn on Time	$I_{C} = 2.5 A$ $I_{C} = 0.5 A$ $V_{CE} = 25 V$ $I_{C} = 5 A$ $I_{B1} = 1 A$	V _{CE} = 10 V V _{CE} = 10 V			2.2	MHz
$\begin{array}{c c} f_{T} & T \\ I_{s/b}^{**} & S \\ C \\ \hline \\ t_{on} \\ \hline \\ t_{s} \\ t_{s} \\ F \end{array}$	Transition Frequency Second Breakdown Collector Current Turn on Time	$I_{C} = 0.5 A$ $V_{CE} = 25 V$ $I_{C} = 5 A$ $I_{B1} = 1 A$	V _{CE} = 10 V		10		
Is/b**StonTtsStsF	Second Breakdown Collector Current Turn on Time	V _{CE} = 25 V I _C = 5 A I _{B1} = 1 A	01610	4	10	J.C.	
t _s F	Collector Current Turn on Time	I _C = 5 A I _{B1} = 1 A	V _{CE} = 250 V	4	$O_{Q_{\ell}}$		A
t _{on} t _s S t _s F		I _{B1} = 1 A	V _{CE} = 250 V	01			
t _s F	Storage Time				0.2		μs
	Fall Time	$I_{C} = 5 A$ $I_{B1} = -I_{B2} = 1 A$	V _{CE} = 250 V			1.7 0.3	μs μs
t _f F			V _{CE} = 40 V			1	μs
psole	Fall Time duration = 300 µs, duty cycle 1 on repetitive pulse.	ct(S)					

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TO-3 MECHANICAL DATA

DIM.	mm		inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А	11.00		13.10	0.433		0.516
В	0.97		1.15	0.038		0.045
С	1.50		1.65	0.059		0.065
D	8.32		8.92	0.327		û.351
E	19.00		20.00	0.748		0.787
G	10.70		11.10	0.421		0.437
Ν	16.50		17.20	0.649		0.677
Р	25.00		26.00	0.584	201	1.023
R	4.00		4.09	0.157	2100	0.161
U	38.50		(19.30	1.515		1.547
V	30.00		30.30	1.187		1.193



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